



JST01V-AC6

m 8837

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SS01V -

Peak pulse voltage
(T_j -

ORDERING INFORMATION

J	ST	01	V	-600	SW
JieJie Microelectronics Co., Ltd.	Triacs	$I_{T(RMS)}:1A$	$V:SOT-223$	$600:V_{DRM}/V_{RRM} \quad 600V$	$SW:I_{GT1-3} \quad 10mA$

MARKING

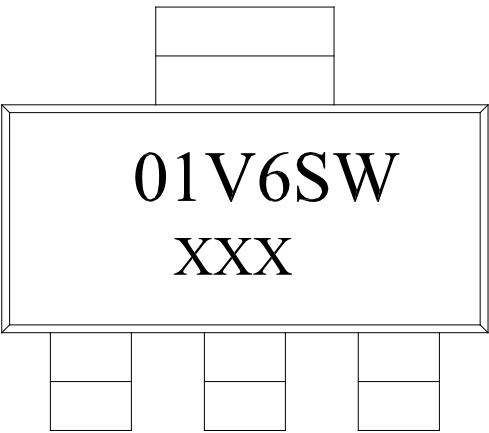


FIG.1: Maximum power dissipation versus RMS

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

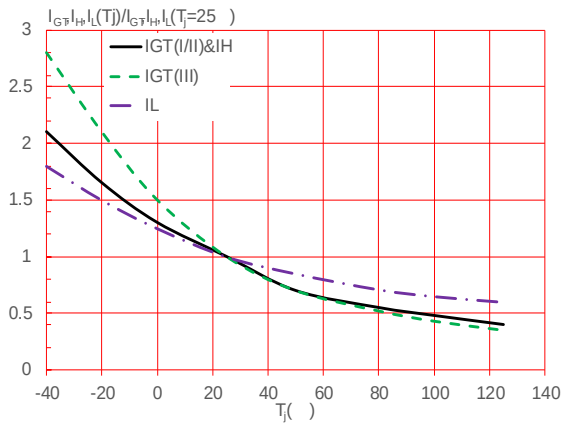
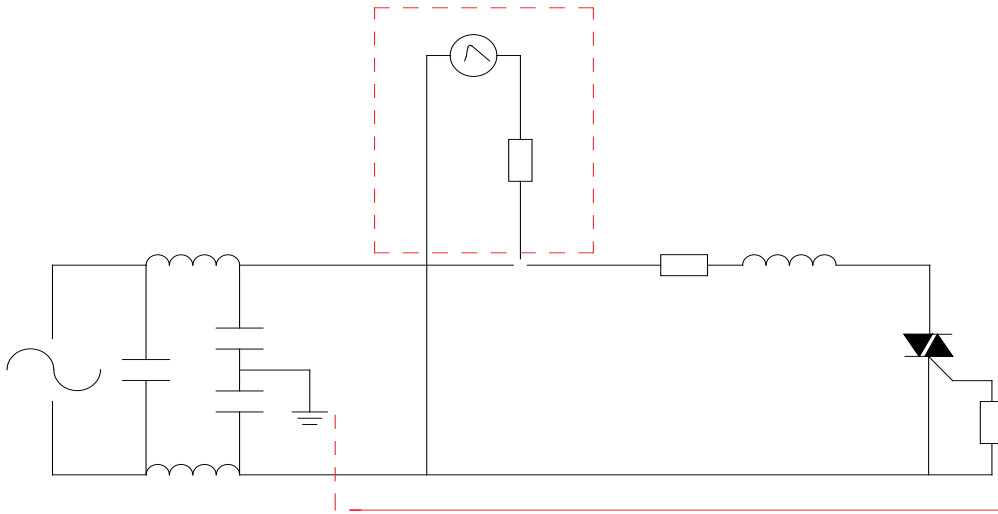


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



JST01V-

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